

### Questions 1-25 carry 1 mark each

1. Consider a system of linear equations:

$$x - 2y + 3z = -1$$

$$x - 3y + 4z = 1$$

$$-2x + 4y - 6z = k$$

The value of  $k$  for which the system has infinitely many solutions is \_\_\_\_\_.

2. A function  $f(x) = 1 - x^2 + x^3$  is defined in the closed interval  $[-1, 1]$ . The value of  $x$ , in the open interval  $(-1, 1)$  for which the mean value theorem is satisfied, is
- (a)  $-\frac{1}{2}$       (b)  $-\frac{1}{3}$       (c)  $\frac{1}{3}$       (d)  $\frac{1}{2}$

3. Suppose  $A$  and  $B$  are two independent events with probabilities  $P(A) \neq 0$  and  $P(B) \neq 0$ . Let  $\bar{A}$  and  $\bar{B}$  be their complements. Which one of the following statements is FALSE?

- (a)  $P(A \cap B) = P(A)P(B)$       (b)  $P(A \cup B) = P(A) + P(B)$   
(c)  $P(A|B) = P(A)$       (d)  $P(\bar{A} \cap \bar{B}) = P(\bar{A})P(\bar{B})$

4. Let  $z = x + iy$  be a complex variable. Consider that contour integration is performed along the unit circle in anticlockwise direction. Which one of the following statements is **NOT TRUE**?

- (a) The residue of  $\frac{z}{z^2 - 1}$  at  $z = 1$  is  $\frac{1}{2}$

(b)  $\oint_C z^2 dz = 0$

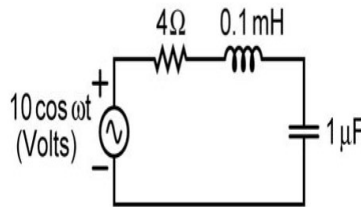
(c)  $\frac{1}{2\pi i} \oint_C \frac{1}{z} dz$

- (d)  $\bar{z}$  (complex conjugate of  $z$ ) is an analytical function

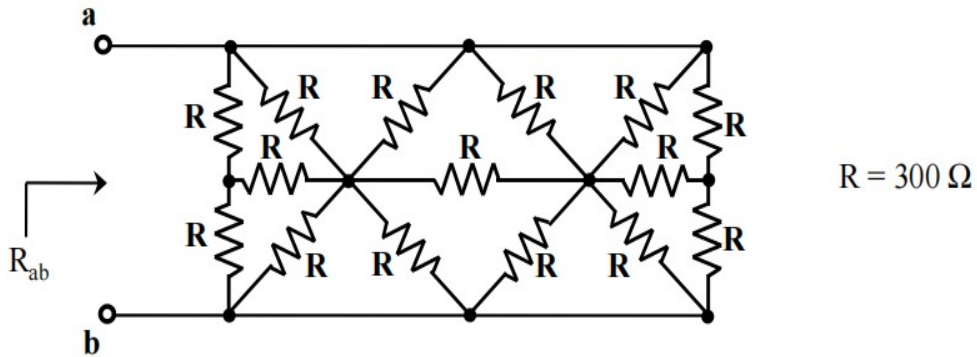
5. The value of  $p$  such that the vector  $\begin{bmatrix} 1 \\ 2 \\ 3 \end{bmatrix}$  is an eigenvector of the matrix

$$\begin{bmatrix} 4 & 1 & 2 \\ p & 2 & 1 \\ 14 & -4 & 10 \end{bmatrix} \text{ is } \underline{\hspace{2cm}}.$$

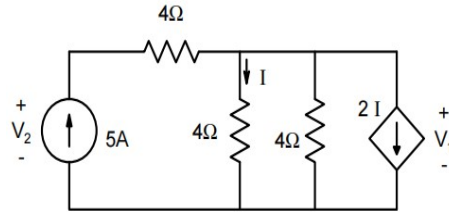
6. In the circuit shown, at resonance, the amplitude of the sinusoidal voltage (in Volts) across the capacitor is \_\_\_\_\_.



7. In the network shown in the figure, all resistors are identical with  $R = 300\Omega$ . The resistance  $R_{ab}$  (in  $\Omega$ ) of the network is \_\_\_\_\_.

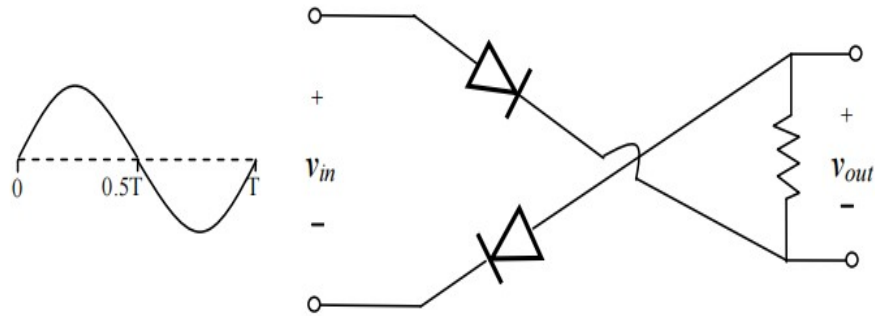


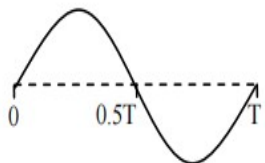
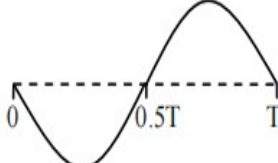
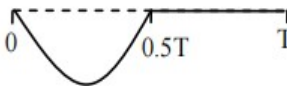
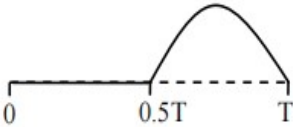
8. In the given circuit, the values of  $V_1$  and  $V_2$  respectively are



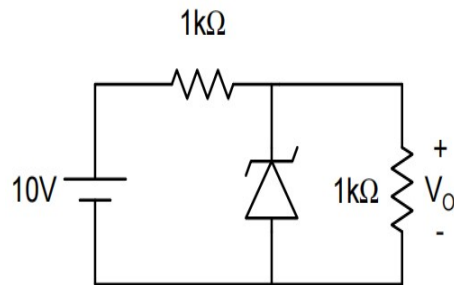
- (a) 5V, 25V      (b) 10V, 30V      (c) 15V, 35V      (d) 0V, 20V
9. A region of negative differential resistance is observed in the current voltage characteristics of a silicon PN junction if
- (a) both the P-region and the N-region are heavily doped
  - (b) the N-region is heavily doped compared to the P-region
  - (c) the P-region is heavily doped compared to the N-region
  - (d) an intrinsic silicon region is inserted between the P-region and the N-region
10. A silicon sample is uniformly doped with donor type impurities with a concentration of  $10^{16}/cm^3$ . The electron and hole mobilities in the sample are  $1200cm^2/V-s$  and  $400cm^2/V-s$  respectively. Assume complete ionization of impurities. The charge of an electron is  $1.6 \times 10^{-19}C$ . The resistivity of the sample (in  $\Omega - cm$ ) is \_\_\_\_\_.

11. For the circuit with ideal diodes shown in the figure, the shape of the output ( $v_{out}$ ) for the given sine wave input ( $v_{in}$ ) will be

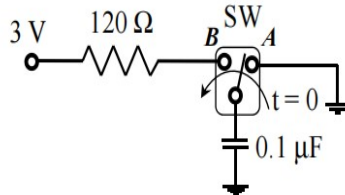


- a) 
- b) 
- c) 
- d) 

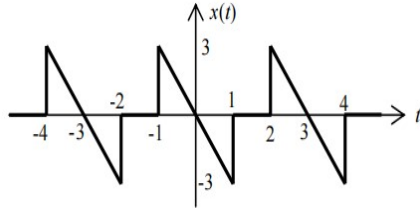
12. In the circuit shown below, the Zener diode is ideal and the Zener voltage is 6V. The output voltage  $V_o$  (in volts) is \_\_\_\_.



13. In the circuit shown, the switch SW is thrown from position A to position B at time  $t = 0$ . The energy ( $\text{in } \mu\text{J}$ ) taken from the  $3\text{V}$  source to charge the  $0.1\mu\text{F}$  capacitor from  $0\text{V}$  to  $3\text{V}$  is



- (a) 0.3              (b) 0.45              (c) 0.9              (d) 3
14. In an 8085 microprocessor, the shift registers which store the result of an addition and the overflow bit are, respectively
- (a) B and F  
(b) A and F  
(c) H and F  
(d) A and C
15. A  $16\text{Kb}$  ( $=16,384$  bit) memory array is designed as a square with an aspect ratio of one (number of rows is equal to the number of columns). The minimum number of address lines needed for the row decoder is \_\_\_\_\_.
16. Consider a four bit D to A converter. The analog value corresponding to digital signals of values 0000 and 0001 are  $0\text{V}$  and  $0.0625\text{V}$  respectively. The analog value (in Volts) corresponding to the digital signal 1111 is \_\_\_\_\_.
17. The result of the convolution  $x(-t) * \delta(-t - t_0)$  is
- (a)  $x(t + t_0)$               (b)  $x(t - t_0)$               (c)  $x(-t + t_0)$               (d)  $x(-t - t_0)$
18. The waveform of a periodic signal  $x(t)$  is shown in the figure



A signal  $g(t)$  is defined by  $g(t) = x\left(\frac{t-1}{2}\right)$ . The average power of  $g(t)$  is \_\_\_\_\_.

19. Negative feedback in a closed-loop control system **DOES NOT**

- (a) reduce the overall gain
- (b) reduce bandwidth
- (c) improve disturbance rejection
- (d) reduce sensitivity to parameter variation

20. A unity negative feedback system has the open-loop transfer function  $G(s) = \frac{K}{s(s+1)(s+3)}$ . The value of the gain  $K (> 0)$  at which the root locus crosses the imaginary axis is \_\_\_\_\_.

21. The polar plot of the transfer function

$$G(s) = \frac{10(s+1)}{s(s+10)} \quad \text{for } 0 \leq \omega < \infty$$

will be in the

- (a) first quadrant
- (b) second quadrant
- (c) third quadrant
- (d) fourth quadrant

22. A sinusoidal signal of  $2\text{ kHz}$  frequency is applied to a delta modulator. The sampling rate and step-size  $\Delta$  of the delta modulator are  $20,000$

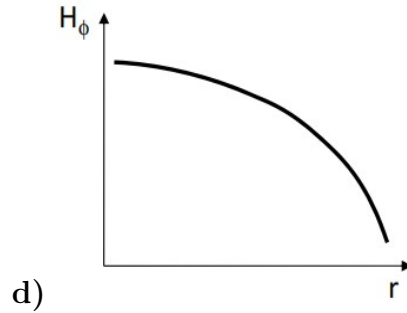
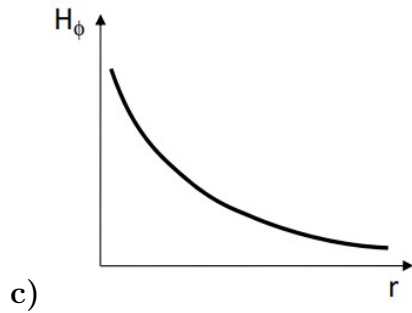
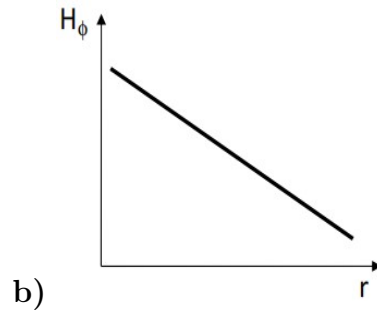
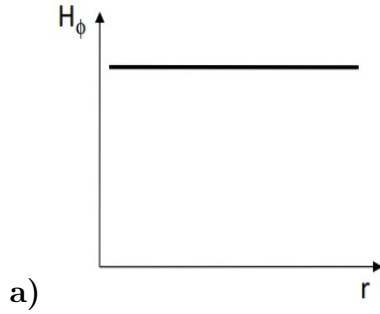
samples per second and  $0.1V$ , respectively. To prevent slope overload, the maximum amplitude of the sinusoidal signal (in Volts) is

- (a)  $\frac{1}{2\pi}$       (b)  $\frac{1}{\pi}$       (c)  $\frac{2}{\pi}$       (d)  $\pi$

23. Consider the signal  $s(t) = m(t) \cos(2\pi f_c t) + \hat{m}(t) \sin(2\pi f_c t)$  where  $\hat{m}(t)$  denotes the Hilbert transform of  $m(t)$  and the bandwidth of  $m(t)$  is very small compared to  $f_c$ . The signal  $s(t)$  is a

- (a) high-pass signal  
 (b) low-pass signal  
 (c) band-pass signal  
 (d) double sideband suppressed carrier signal

24. Consider a straight, infinitely long, current carrying conductor lying on the  $z$ -axis. Which one of the following plots (in linear scale) qualitatively represents the dependence of  $H_\phi$  on  $r$ , where  $H_\phi$  is the magnitude of the azimuthal component of magnetic field outside the conductor and  $r$  is the radial distance from the conductor?



25. The electric field component of a plane wave traveling in a lossless dielectric medium is given by  $\vec{E}(z, t) = \hat{a}_y 2 \cos\left(10^8 t - \frac{z}{\sqrt{2}}\right) V/m$ . The wavelength (in m) for the wave is \_\_\_\_\_.

**Questions 26-55 carry 2 marks each**

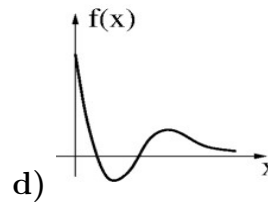
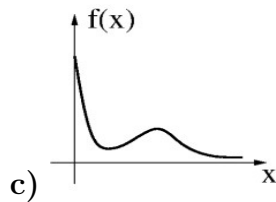
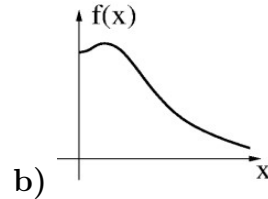
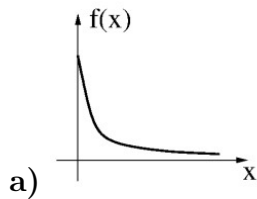
26. The solution of the differential equation  $\frac{d^2 y}{dt^2} + 2\frac{dy}{dt} + y = 0$  with  $y(0) = y'(0) = 1$  is

- (a)  $(2 - t)e^t$  (b)  $(1 + 2t)e^{-t}$   
(c)  $(2 + t)e^{-t}$  (d)  $(1 - 2t)e^t$

27. A vector  $\vec{P}$  is given by  $\vec{P} = x^3 y \vec{a}_x - x^2 y^2 \vec{a}_y - x^2 y x \vec{a}_z$ . Which one of the following statements is **TRUE**?

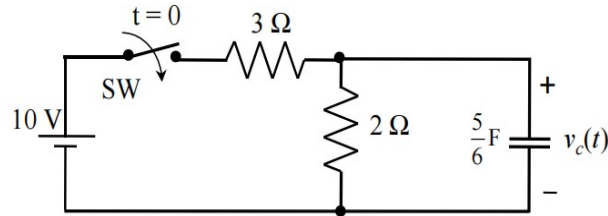
- (a)  $\vec{P}$  is solenoidal, but not irrotational  
(b)  $\vec{P}$  is irrotational, but not solenoidal  
(c)  $\vec{P}$  is neither solenoidal nor irrotational  
(d)  $\vec{P}$  is both solenoidal and irrotational

28. Which one of the following graphs describes the function  $f(x) = e^{-x}(x^2 + x + 1)$ ?

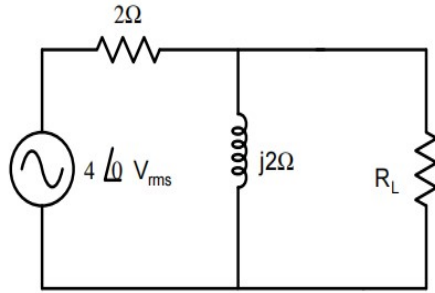




29. The maximum area (in square unit) of a rectangle whose vertices lie on the ellipse  $x^2 + 4y^2 = 1$  is \_\_\_\_.
30. The damping ratio of a series  $RLC$  circuit can be expressed as
- (a)  $\frac{R^2C}{2L}$       (b)  $\frac{2L}{R^2C}$       (c)  $\frac{R}{2}\sqrt{\frac{C}{L}}$       (d)  $\frac{2}{R}\sqrt{\frac{L}{C}}$
31. In the circuit shown, switch SW is closed at  $t = 0$ . Assuming zero initial conditions, the value of  $v_c(t)$  (in Volts) at  $t = 1$  sec is \_\_\_\_.

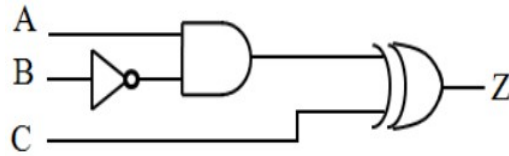


32. In the given circuit, the maximum power (in Watts) that can be transferred to the load  $R_L$  is  $(C_J)$



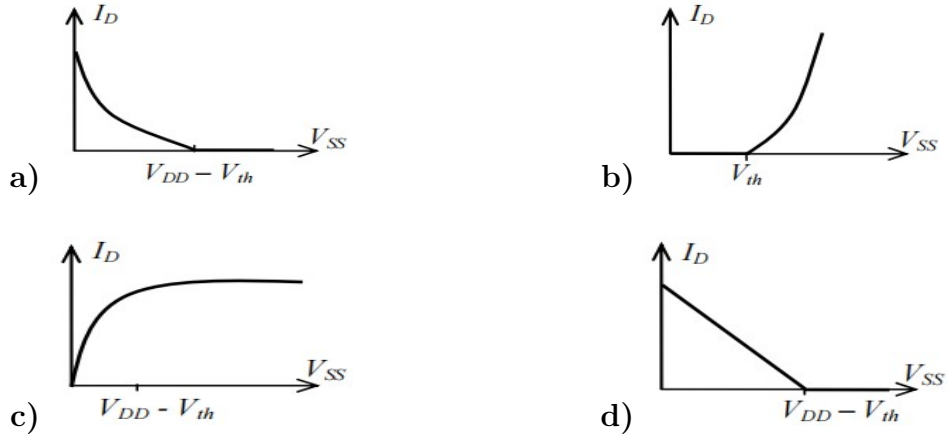
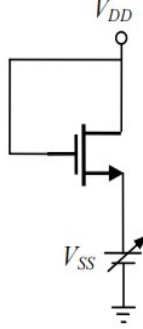
33. The built-in potential of an abrupt p-n junction is  $0.75V$ . If its junction capacitance ( $C_J$ ) at a reverse bias ( $V_R$ ) of  $1.25V$  is  $5pF$ , the value of  $C_J$  (in pF) when  $V_R = 7.25V$  is \_\_\_\_.
34. A MOSFET in saturation has a drain current of  $1mA$  for  $V_{DS} = 0.5V$ . If the channel length modulation coefficient is  $0.05V^{-1}$ , the output resistance (in  $k\Omega$ ) of the MOSFET is \_\_\_\_.

35. For a silicon diode with long P and N regions, the acceptor and donor impurity concentrations are  $1 \times 10^{17} \text{ cm}^{-3}$  and  $1 \times 10^{15} \text{ cm}^{-3}$ , respectively. The lifetimes of electrons in P region and holes in N region are both  $100 \mu\text{s}$ . The electron and hole diffusion coefficients are  $49 \text{ cm}^2/\text{s}$  and  $36 \text{ cm}^2/\text{s}$ , respectively. Assume  $kT/q = 26 \text{ mV}$ , the intrinsic carrier concentration is  $1 \times 10^{10} \text{ cm}^{-3}$ , and  $q = 1.6 \times 10^{-19} \text{ C}$ . When a forward voltage of  $208 \text{ mV}$  is applied across the diode, the hole current density (in  $\text{nA/cm}^2$ ) injected from P region to N region is \_\_\_\_\_.
36. The Boolean expression  $F(X, Y, Z) = \overline{X}Y\overline{Z} + X\overline{Y}\overline{Z} + XY\overline{Z} + XYZ$  converted into the canonical product of sum (POS) form is
- $(X + Y + Z)(X + Y + \overline{Z})(X + \overline{Y} + \overline{Z})(\overline{X} + Y + \overline{Z})$
  - $(X + \overline{Y} + Z)(\overline{X} + Y + \overline{Z})(\overline{X} + \overline{Y} + Z)(\overline{X} + \overline{Y} + \overline{Z})$
  - $(X + Y + Z)(\overline{X} + Y + \overline{Z})(X + \overline{Y} + Z)(\overline{X} + \overline{Y} + \overline{Z})$
  - $(X + \overline{Y} + \overline{Z})(\overline{X} + Y + Z)(\overline{X} + \overline{Y} + Z)(X + Y + Z)$
37. All the logic gates shown in the figure have a propagation delay of  $20 \text{ ns}$ . Let  $A = C = 0$  and  $B = 1$  until time  $t = 0$ . At  $t = 0$ , all the inputs flip (i.e.,  $A = C = 1$  and  $B = 0$ ) and remain in that state. For  $t > 0$ , output  $Z = 1$  for a duration (in  $\text{ns}$ ) of \_\_\_\_\_.

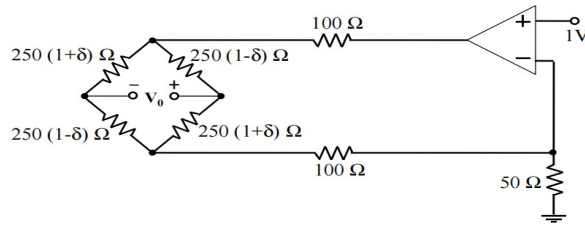


38. A 3-input majority gate is defined by the logic function  $M(a, b, c) = ab + bc + ca$ . Which one of the following gates is represented by the function  $M(\overline{M(a, b, c)}, M(a, b, \overline{c}), c)$ ?
- 3-input NAND gate
  - 3-input XOR gate
  - 3-input NOR gate
  - 3-input XNOR gate

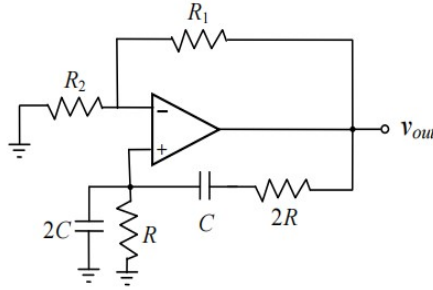
39. For the NMOSFET in the circuit shown, the threshold voltage is  $V_{th}$ , where  $V_{th} > 0$ . The source voltage  $V_{SS}$  is varied from 0 to  $V_{DD}$ . Neglecting the channel length modulation, the drain current  $I_d$  as a function of  $V_{SS}$  is represented by



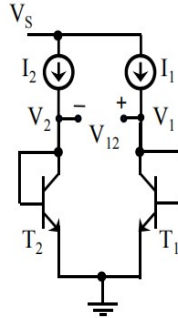
40. In the circuit shown, assume that the opamp is ideal. The bridge output voltage  $V_0$  (in  $mV$ ) for  $\delta = 0.05$  is \_\_\_\_.



41. The circuit shown in the figure has an ideal opamp. The oscillation frequency and the condition to sustain the oscillations, respectively, are



- (a)  $\frac{1}{CR}$  and  $R_1 = R_2$                       (b)  $\frac{1}{CR}$  and  $R_1 = 4R_2$   
(c)  $\frac{1}{2CR}$  and  $R_1 = R_2$                       (d)  $\frac{1}{2CR}$  and  $R_1 = 4R_2$
42. In the circuit shown,  $I_1 = 80\text{mA}$  and  $I_2 = 4\text{mA}$ . Transistors  $T_1$  and  $T_2$  are identical. Assume that the thermal voltage  $V_T$  is  $26\text{mV}$  at  $27^\circ\text{C}$ . At  $50^\circ\text{C}$ , the value of the voltage  $V_{12}$  (in  $\text{mV}$ ) is \_\_\_\_\_.



43. Two sequences  $[a, b, c]$  and  $[A, B, C]$  are related as

$$\begin{bmatrix} A \\ B \\ C \end{bmatrix} = \begin{bmatrix} 1 & 1 & 1 \\ 1 & W_3^{-1} & W_3^{-2} \\ 1 & W_3^{-2} & W_3^{-4} \end{bmatrix} \begin{bmatrix} a \\ b \\ c \end{bmatrix} \text{ where } W_3 = e^{j\frac{2\pi}{3}}.$$

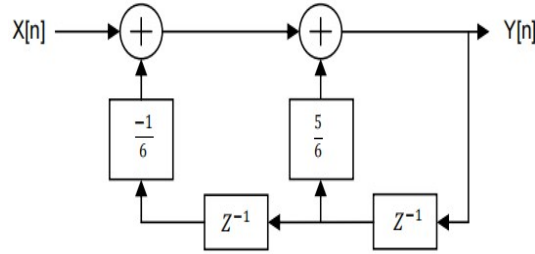
If another sequence  $[p, q, r]$  is derived as,

$$\begin{bmatrix} p \\ q \\ r \end{bmatrix} = \begin{bmatrix} 1 & 1 & 1 \\ 1 & W_3^1 & W_3^2 \\ 1 & W_3^2 & W_3^4 \end{bmatrix} \begin{bmatrix} 1 & 0 & 0 \\ 0 & W_3^2 & 0 \\ 0 & 0 & W_3^4 \end{bmatrix} \begin{bmatrix} A/3 \\ B/3 \\ C/3 \end{bmatrix}$$

then the relationship between sequence  $[p, q, r]$  and  $[a, b, c]$  is

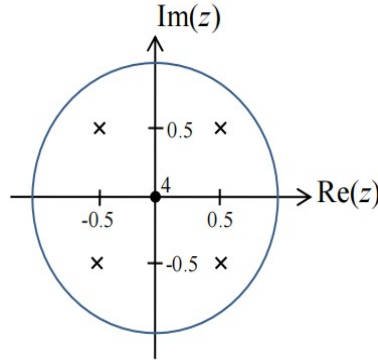
- (a)  $[p, q, r] = [b, a, c]$  (b)  $[p, q, r] = [b, c, a]$   
(c)  $[p, q, r] = [c, a, b]$  (d)  $[p, q, r] = [c, b, a]$

44. For the discrete-time system shown in the figure, the poles of the system transfer function are located at

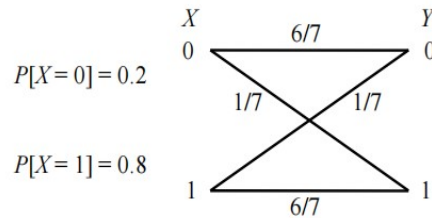


- (a) 2, 3 (b)  $\frac{1}{2}, 3$  (c)  $\frac{1}{2}, \frac{1}{3}$  (d)  $2, \frac{1}{3}$

45. The pole-zero diagram of a causal and stable discrete-time system is shown in the figure. The zero at the origin has multiplicity 4. The impulse response of the system is  $h[n]$ . If  $h[0] = 1$ , we can conclude,

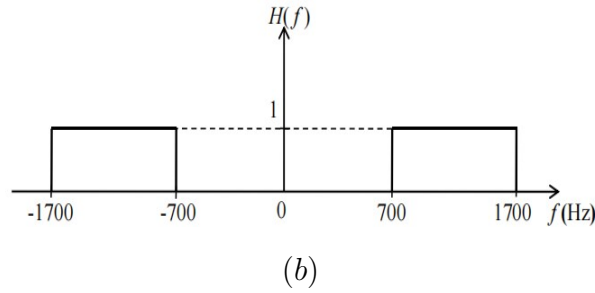
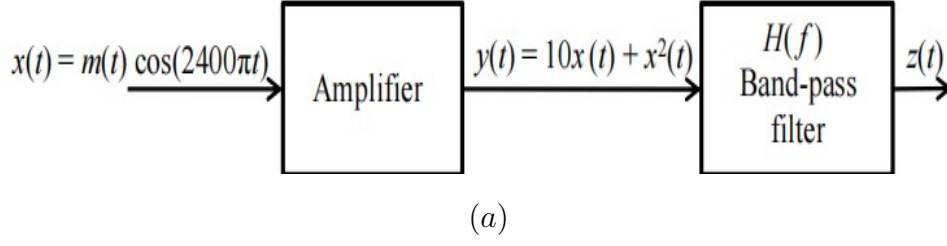


- (a)  $h[n]$  is real for all  $n$   
 (b)  $h[n]$  is purely imaginary for all  $n$   
 (c)  $h[n]$  is real for only even  
 (d)  $h[n]$  is purely imaginary for only odd
46. The open-loop transfer function of a plant in a unity feedback configuration is given as  $G(s) = \frac{K(s+4)}{(s+8)(s^2-9)}$ . The value of the gain  $K (> 0)$  for which  $-1 + j2$  lies on the root locus is \_\_\_\_.
47. A lead compensator network includes a parallel combination of R and C in the feed-forward path. If the transfer function of the compensator is  $G_c(s) = \frac{s+2}{s+4}$ , the value of RC is \_\_\_\_.
48. A plant transfer function is given as  $G_c(s) = \left(K_P + \frac{K_I}{s}\right) \frac{1}{s(s+2)}$ . When the plant operates in a unity feedback configuration, the condition for the stability of the closed loop system is  
 (a)  $K_p > \frac{K_I}{2} > 0$  (b)  $2K_I > K_p > 0$  (c)  $2K_I < K_p$  (d)  $2K_I > K_p$
49. The input  $X$  to the Binary Symmetric Channel(BSC) shown in the figure is '1' with probability 0.8. The cross-over probability is  $1/7$ . If the received bit  $Y = 0$ , the conditional probability that '1' was transmitted is \_\_\_\_.



50. The transmitted signal in a GSM system is of 200 kHz bandwidth and 8 users share a common bandwidth using TDMA. If at a given time 12 users are talking in a cell, the total bandwidth of the signal received by the base station of the cell will be at least (in kHz) \_\_\_\_\_.

51. In the system shown in Figure(a),  $m(t)$  is a low-pass signal with bandwidth  $W$  Hz. The frequency response of the band-pass filter  $H(f)$  is shown in Figure(b). If it is desired that the output signal  $z(t) = 10x(t)$ , the maximum value of  $W$  (Hz) should be strictly less than \_\_\_\_\_.



52. A source emits bit 0 with probability  $\frac{1}{3}$  and bit 1 with probability  $\frac{2}{3}$ . The emitted bits are communicated to the receiver. The receiver decides for either 0 or 1 based on the received value  $R$ . It is given that the conditional density functions of  $R$  are as

$$f_{R|0}(r) = \begin{cases} \frac{1}{4}, & -3 \leq r \leq 1 \\ 0 & \text{otherwise.} \end{cases} \quad \text{and} \quad f_{R|1}(r) = \begin{cases} \frac{1}{6}, & -1 \leq r \leq 5 \\ 0 & \text{otherwise.} \end{cases}$$

The minimum decision error probability is

- (a) 0                      (b) 1/12                      (c) 1/9                      (d) 1/6
53. The longitudinal component of the magnetic field inside an air-filled rectangular waveguide made of a perfect electric conductor is given by

the following expression

$$H_z(x, y, z, t) = 0.1 \cos(25\pi x) \cos(30.3\pi y) \cos(12y \times 10^9 t - \beta z) \text{ (A/m)}$$

The cross-sectional dimensions of the waveguide are given as  $a = 0.08\text{m}$  and  $b = 0.033\text{m}$ . The mode of propagation inside the waveguide is

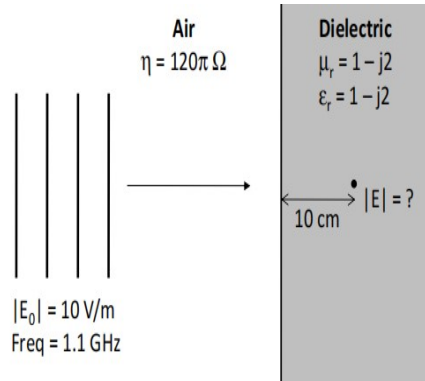
- (a)  $TM_{12}$  (b)  $TM_{21}$   
(c)  $TE_{21}$  (d)  $TE_{12}$

54. The electric field intensity of a plane wave traveling in free space is given by the following expression

$$\mathbf{E}(x, t) = \mathbf{a}_y 24\pi \cos(\omega t - k_0 x) \text{ (V/m)}$$

In this field, consider a square area  $10\text{cm} \times 10\text{cm}$  on a plane  $x + y = 1$ . The total time-averaged power (in mW) passing through the square area is \_\_\_\_\_.

55. Consider a uniform plane wave with amplitude ( $E_0$ ) of  $10\text{V/m}$  and  $1.1\text{GHz}$  frequency travelling in air, and incident normally on a dielectric medium with complex relative permittivity ( $\epsilon_r$ ) and permeability ( $\mu_r$ ) as shown in the figure.



The magnitude of the transmitted electric field component ( $\text{in V/m}$ ) after it has travelled a distance of  $10 \text{ cm}$  inside the dielectric region is \_\_\_\_\_.